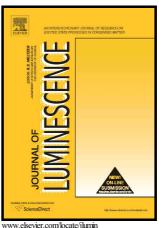
Author's Accepted Manuscript

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PII: S0022-2313(18)30328-4

DOI: https://doi.org/10.1016/j.jlumin.2018.05.013

Reference: **LUMIN15595**

To appear in: Journal of Luminescence

Received date: 19 February 2018

3 May 2018 Revised date: Accepted date: 6 May 2018

Cite this article as: Jianyue He, Zhiwen Gao, Shihua Liu, Jung Hyun Jeong, Ruijin Yu and Bin Deng, New Eu³⁺-activated bismuthate tellurate LiSrBiTeO₆ red-emitting phosphor for InGaN-based w-LEDs, Journal of Luminescence, https://doi.org/10.1016/j.jlumin.2018.05.013

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ACCEPTED MANUSCRIPT

New Eu³⁺-activated bismuthate tellurate LiSrBiTeO₆ red-emitting phosphor for InGaN-based w-LEDs

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Abstract:

A series of novel Eu³⁺-doped LiSrBiTeO₆ red-emitting phosphors were prepared by the solid-state reaction method for the first time. Its crystal structure and luminescence properties are investigated. X-ray powder diffraction patterns in combination with the Rietveld method reveal its single phase structure. The phosphor can be efficiently excited by 394 nm and 465 nm light and emits bright red luminescence at 616 nm corresponding to the electric dipole transition ⁵D₀–⁷F₂. The optimal doping concentration of LiSrBi_{1-x}TeO₆:xEu³⁺ is about 40 mol%. The thermal stability of the phosphor was tested by measuring their temperature-dependent emission intensities. The warm white light LEDs was fabricated based on the InGaN-chip. The chromaticity coordinates of fabricated w-LED are (0.344, 0.381). All results indicated that LiSrBiTeO₆:Eu³⁺ phosphors have potential application as red

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